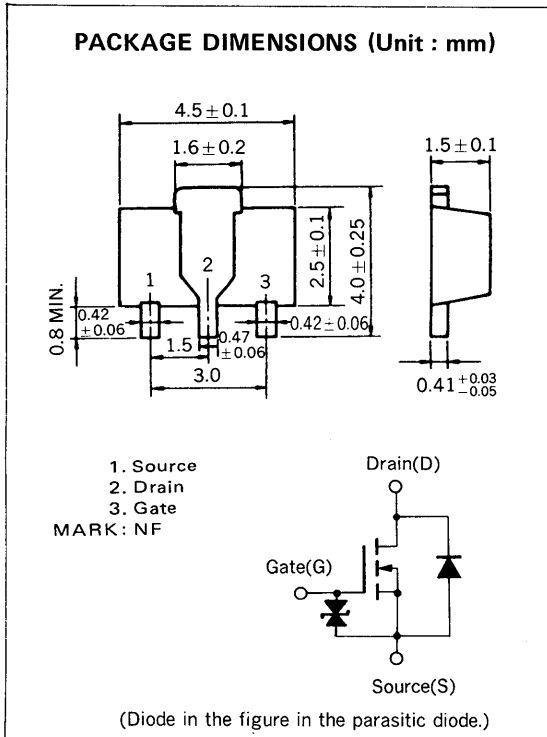


# MOS FIELD EFFECT TRANSISTOR 2SK1587

## N-CHANNEL MOS FET FOR SWITCHING



The 2SK1587 is an N-channel vertical type MOS FET which can be driven by battery voltage (two dry cells).

As the MOS FET has on-state resistance and excellent switching characteristics, it is suitable for driving actuators such as motors, relays, and solenoids.

### FEATURES

- Directly driven by ICs having a 3 V power supply.
- Has low on-state resistance  
 $R_{DS(on)1} = 0.8 \Omega$  MAX. @  $V_{GS} = 2.5$  V,  $I_D = 0.5$  A  
 $R_{DS(on)2} = 0.5 \Omega$  MAX. @  $V_{GS} = 4.0$  V,  $I_D = 1.0$  A

### QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

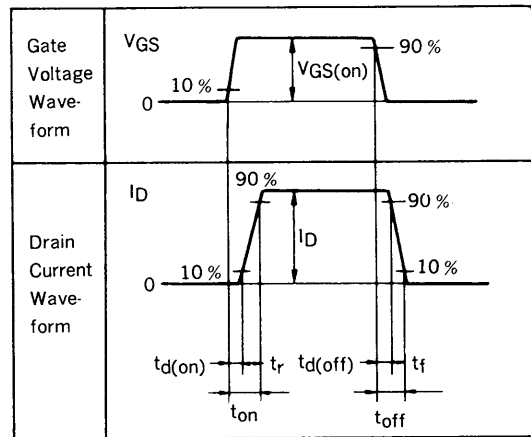
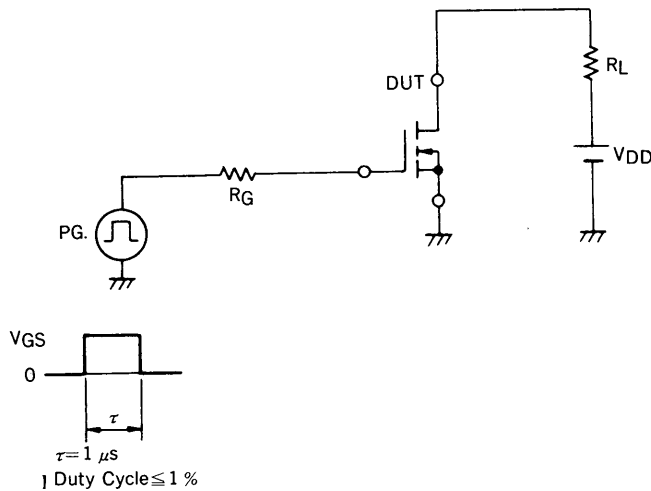
### ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	$V_{DSS}$	16	V	$V_{GS} = 0$
Gate to Source Voltage	$V_{GSS}$	$\pm 16$	V	$V_{DS} = 0$
Drain Current	$I_D(\text{DC})$	$\pm 2.0$	A	
Drain Current	$I_D(\text{pulse})$	$\pm 4.0$	A	$PW \leq 10$ ms, Duty Cycle $\leq 50$ %
Total Power Dissipation	$P_T$	2.0	W	When using ceramic board of $16 \text{ cm}^2 \times 0.7$ mm
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$	
Storage Temperature	$T_{stg}$	$-55$ to $+150$	$^\circ\text{C}$	

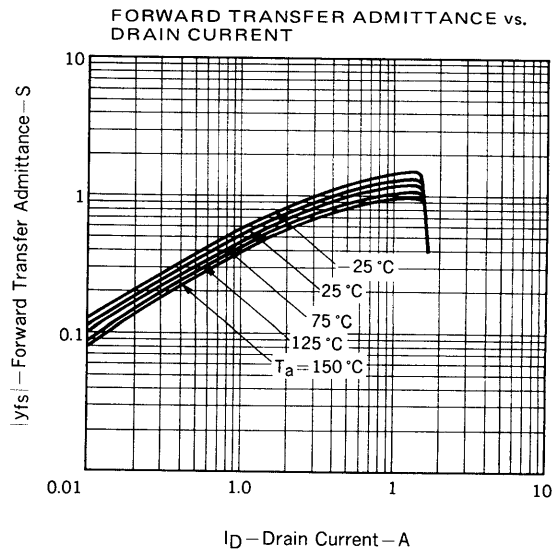
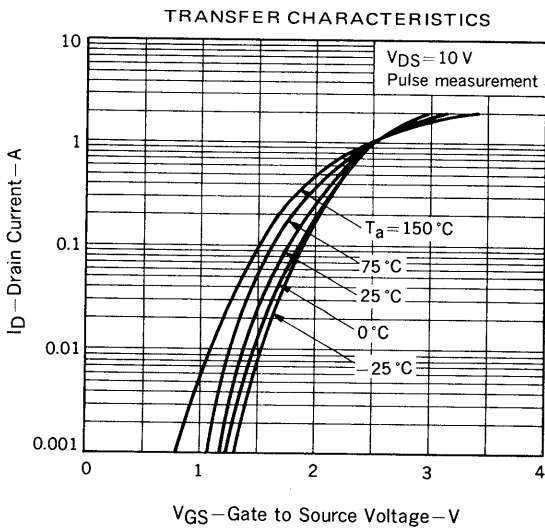
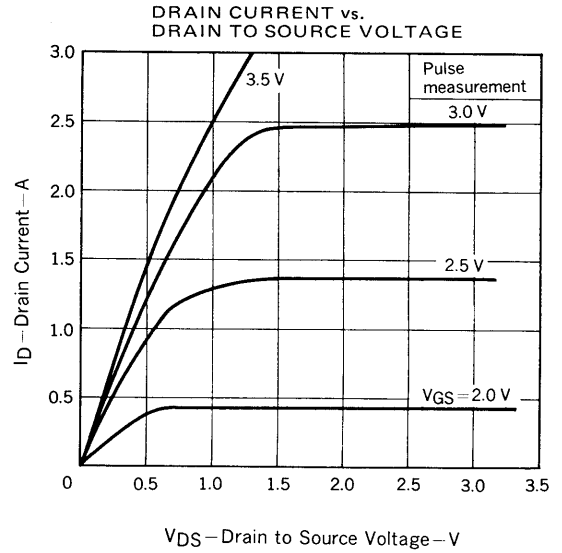
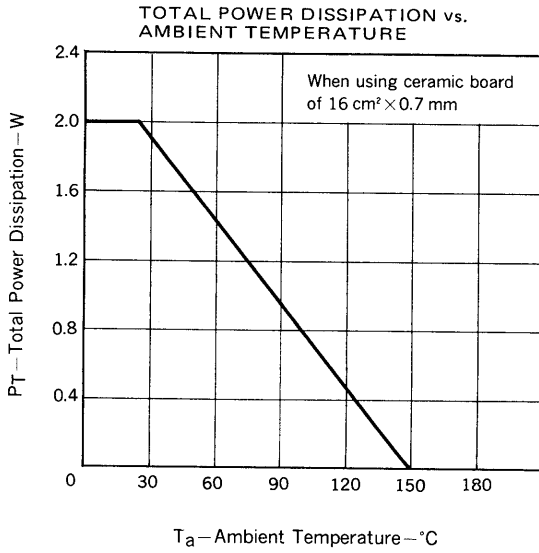
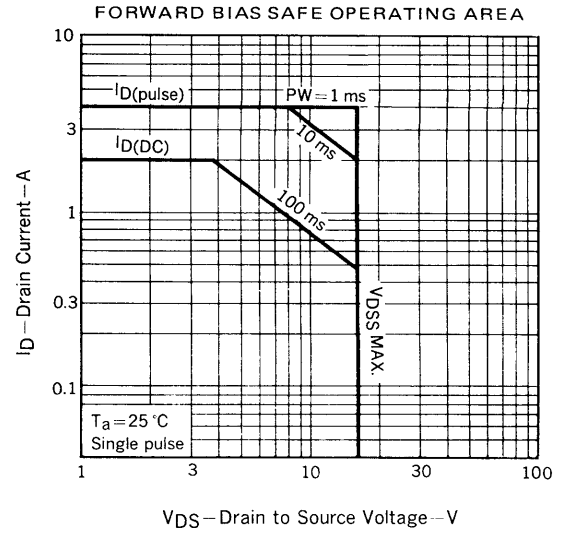
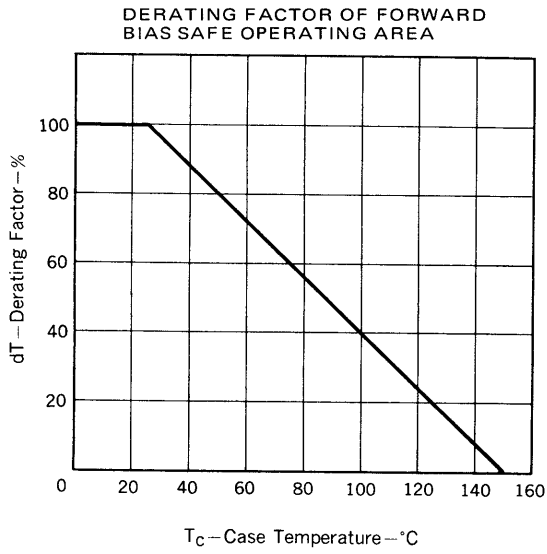
ELECTRICAL CHARACTERISTICS ( $T_a = 25\text{ }^\circ\text{C}$ )

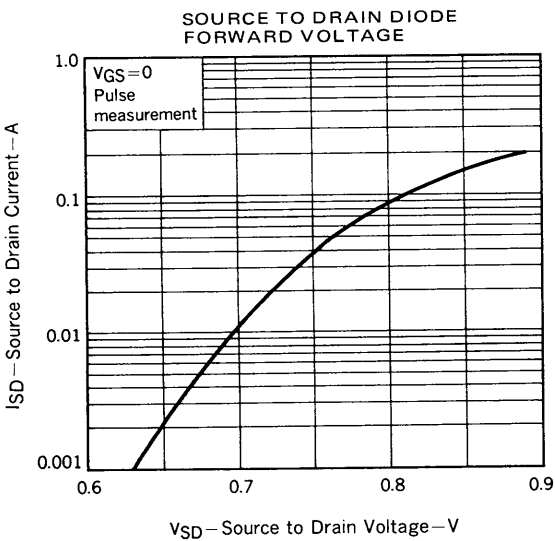
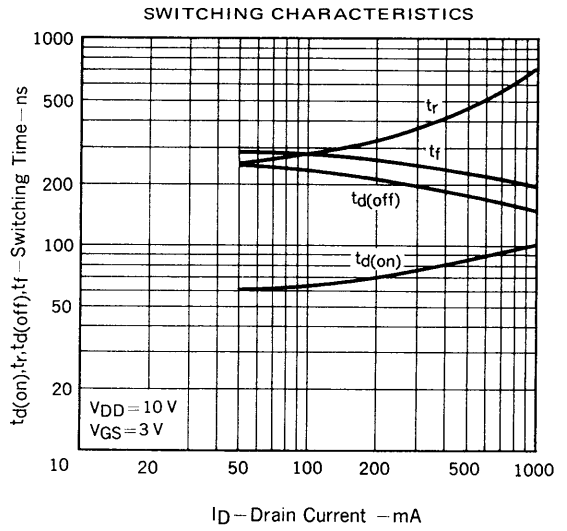
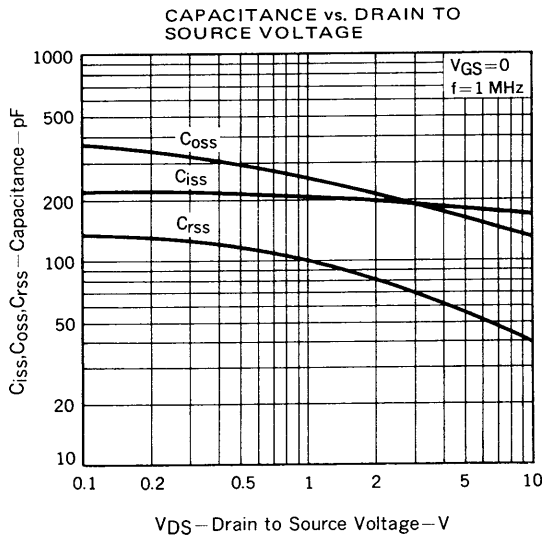
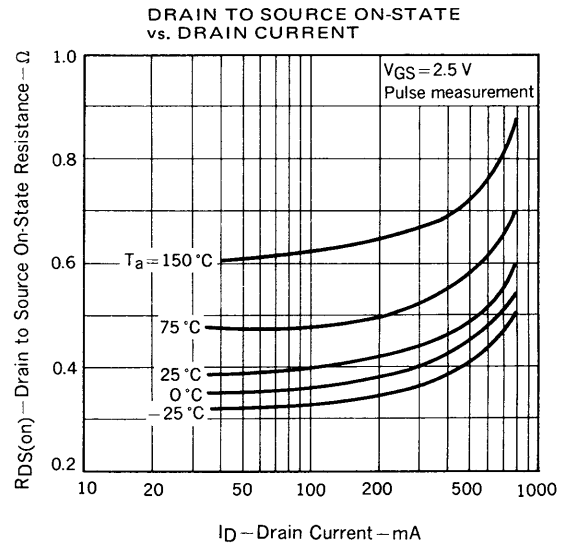
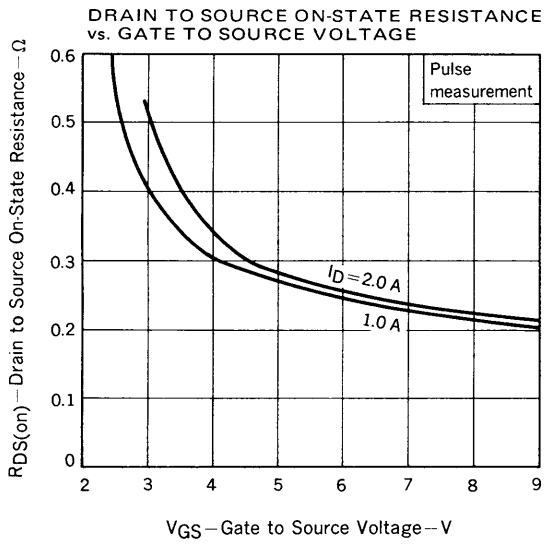
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	$I_{DSS}$			1.0	$\mu\text{A}$	$V_{DS} = 16\text{ V}, V_{GS} = 0$
Gate Leakage Current	$I_{GSS}$			$\pm 5.0$	$\mu\text{A}$	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0$
Gate Cut-off Voltage	$V_{GS(off)}$	0.8	1.2	1.6	V	$V_{DS} = 10\text{ V}, I_D = 1.0\text{ mA}$
Forward Transfer Admittance	$ Y_{fs} $	0.4			S	$V_{DS} = 5.0\text{ V}, I_D = 1.0\text{ A}$
Drain to Source On-State Resistance	$R_{DS(on)1}$		0.5	0.8	$\Omega$	$V_{GS} = 2.5\text{ V}, I_D = 0.5\text{ A}$
Drain to Source On-State Resistance	$R_{DS(on)2}$		0.3	0.5	$\Omega$	$V_{GS} = 4.0\text{ V}, I_D = 1.0\text{ A}$
Input Capacitance	$C_{iss}$		180		pF	$V_{DS} = 5.0\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$
Output Capacitance	$C_{oss}$		160		pF	
Feedback Capacitance	$C_{rss}$		55		pF	
Turn-On Delay Time	$t_{d(on)}$		100		ns	$V_{DD} = 10\text{ V}, I_D = 1.0\text{ A}$ $V_{GS(on)} = 3.0\text{ V}, R_G = 10\ \Omega$ $R_L = 10\ \Omega$
Rise Time	$t_r$		700		$\mu\text{s}$	
Turn-Off Delay Time	$t_{d(off)}$		150		ns	
Fall Time	$t_f$		200		ns	

SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )





**RECOMMENDED SOLDERING CONDITIONS**

Mounting of this product by soldering should be done under the following conditions.

Please consult our representatives about soldering methods and conditions other than these.

**SURFACE MOUNT TYPE**

For details of the recommended soldering conditions, see the information document "SMT MANUAL" (IEI-1207).

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00

\*: Stored days under storage conditions at 25 °C and below 65 % R.H. after the dry-pack has been opened.

**Note 1** Combination of soldering methods should be avoided.

**REFERENCE**

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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